

### FEATURES

- 10-Bit Resolution
- Two Monolithic Complete 10-Bit ADCs
- 40 MSPS Conversion Rate
- On-Chip Track-and-Hold
- On-Chip Voltage Reference
- Low 5 pF Input Capacitance
- TTL/CMOS Outputs
- Tri-State Output Buffers
- Single +3.0V Power Supply Operation
- Low Power Dissipation: 200mW-typ @ 2.7V
- Power Down Mode Less Than 5mW
- -40°C to +85°C Operation Temperature Range

### APPLICATIONS

- Medical Ultrasound Imaging
- I & Q Modems

### BENEFITS

- Reduction of Components
- Reduction of System Cost
- High Performance @ Low Power Dissipation
- Long Term Time and Temperature Stability

### GENERAL DESCRIPTION

The XRD64L42 is two 10-bit, monolithic, 40 MSPS ADCs. Manufactured using a standard CMOS process, the XRD64L42 offers low power, low cost and excellent performance. The on-chip track-and-hold amplifier (T/H) and voltage reference (VREF) eliminate the need for external active components, requiring only an external ADC conversion clock for the application. The XRD64L42 analog input can be driven with ease due to the high input impedance of  $R_{IN} = 25K\Omega$  and  $C_{IN} = 5pF$ .

The design architecture uses 17 time-interleaved 10-bit SAR ADCs in each converter to achieve high conversion rate of 40 MSPS minimum. In order to insure and maintain accurate 10-bit operation with respect to time and temperature, XRD64L42 incorporates an auto-calibration circuit which continuously adjusts and matches the offset and linearity of each

ADC. This auto-calibration circuit is transparent to the user after the initial 3.4ms calibration (168,000 initial clock cycles).

The power dissipation is only 200mW at 40 MSPS with +2.7V power supply.

The digital output data is straight binary format, and the tri-state disable function is provided for common bus interface.

The XRD64L42 internal reference provides cost savings and simplifies the design/development. The output voltage of the internal reference is set by two external resistors. The internal reference can be disabled if an external reference is used for a power savings of 50mW.

### ORDERING INFORMATION

Part Number	Package Type	Temperature Range
XRD64L42AIV	64-Lead TQFP	-40°C to +85°C

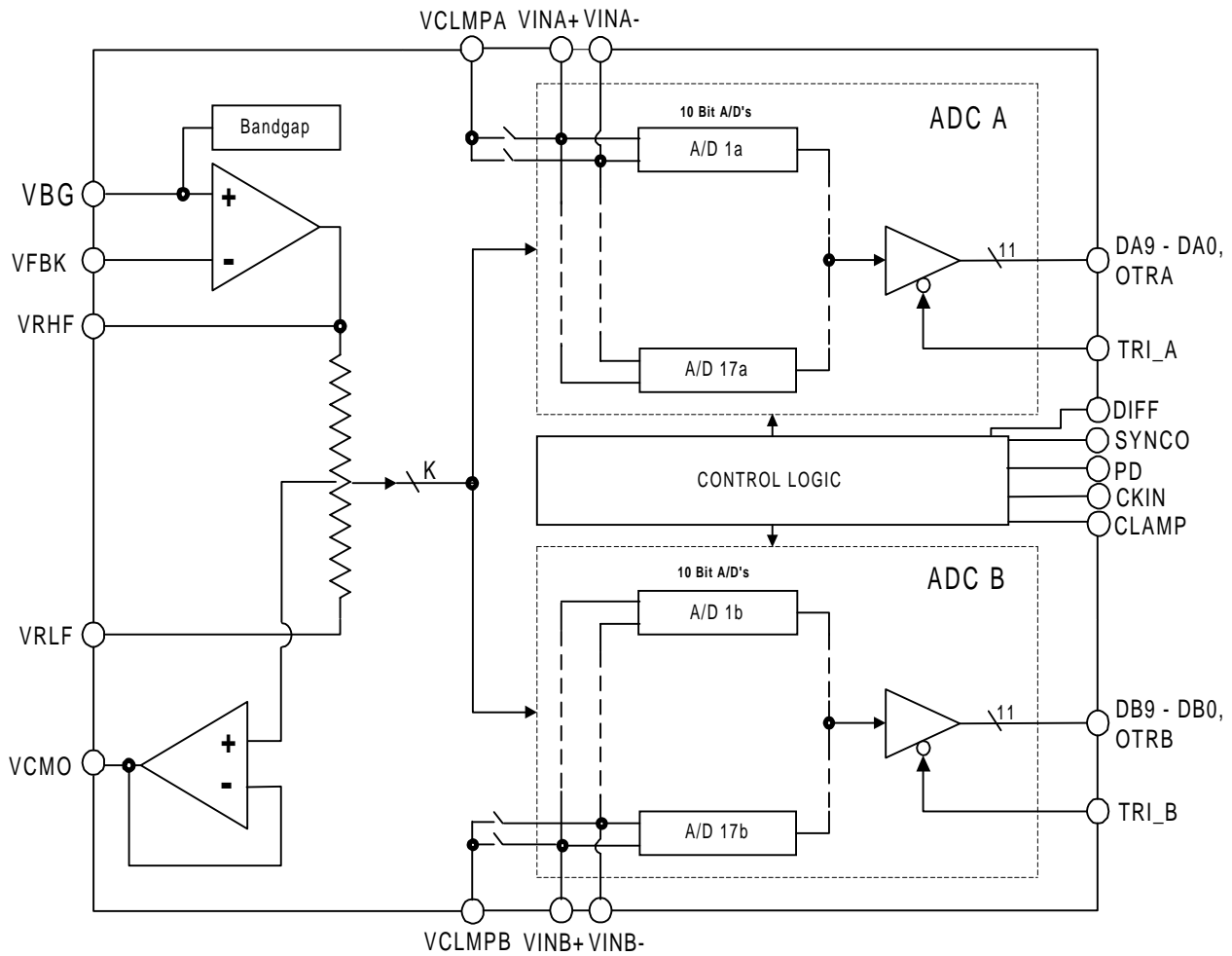
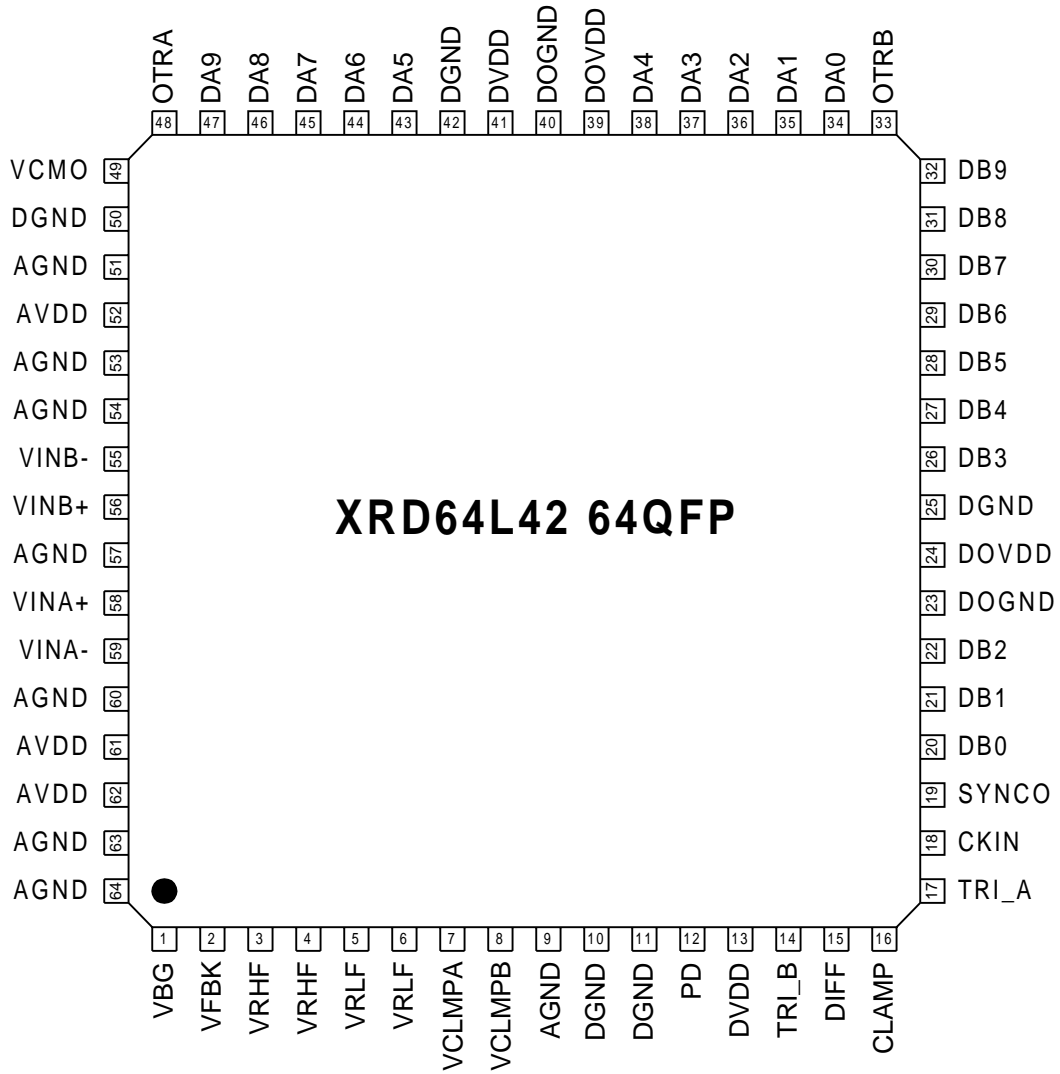


Figure 1. XRD64L42 Simplified Block Diagram



## PIN DESCRIPTION

Pin #	Symbol	Description
1	VBG	Bandgap Voltage Output
2	VFBK	Analog Reference Feedback
3	VRHF	Top Voltage Reference Force
4	VRHF	Top Voltage Reference Force
5	VRLF	Bottom Voltage Reference Force
6	VRLF	Bottom Voltage Reference Force
7	VCLMPA	Analog Input Clamp A
8	VCLMPB	Analog Input Clamp B
9	AGND	Analog Ground
10	DGND	Digital Ground
11	DGND	Digital Ground
12	PD	Power Down
13	DVDD	Digital Supply Voltage
14	TRI_B	Tri-state for the B Channel Outputs
15	DIFF	Differential / Single-Ended Input Mode
16	CLAMP	Digital Clamp Control
17	TRI_A	Tri-state for the A Channel Outputs
18	CKIN	Clock Input
19	SYNCO	Data Valid Output
20	DB0	Digital Output Bit 0 (LSB) ADC B
21	DB1	Digital Output Bit 1 ADC B
22	DB2	Digital Output Bit 2 ADC B
23	DOGND	Digital Output Ground
24	DOVDD	Digital Output Supply Voltage
25	DGND	Digital Ground
26	DB3	Digital Output Bit 3 ADC B
27	DB4	Digital Output Bit 4 ADC B
28	DB5	Digital Output Bit 5 ADC B
29	DB6	Digital Output Bit 6 ADC B
30	DB7	Digital Output Bit 7 ADC B
31	DB8	Digital Output Bit 8 ADC B
32	DB9	Digital Output Bit 9 (MSB) ADC B
33	OTRB	Over Range Digital Output Bit ADC B
34	DA0	Digital Output Bit 0 (LSB) ADC A
35	DA1	Digital Output Bit 1 ADC A
36	DA2	Digital Output Bit 2 ADC A
37	DA3	Digital Output Bit 3 ADC A
38	DA4	Digital Output Bit 4 ADC A
39	DOVDD	Digital Output Supply Voltage
40	DOGND	Digital Output Ground
41	DVDD	Digital Supply Voltage

**PIN DESCRIPTION (CONT'D)**

<b>Pin #</b>	<b>Symbol</b>	<b>Description</b>
42	DGND	Digital Ground
43	DA5	Digital Output Bit 5 ADC A
44	DA6	Digital Output Bit 6 ADC A
45	DA7	Digital Output Bit 7 ADC A
46	DA8	Digital Output Bit 8 ADC A
47	DA9	Digital Output Bit 9 ADC A
48	OTRA	Over Range Digital Output Bit ADC A
49	VCMO	Differential Common Mode Voltage Output
50	DGND	Digital Ground
51	AGND	Analog Ground
52	AVDD	Analog Supply Voltage
53	AGND	Analog Ground
54	AGND	Analog Ground
55	VINB-	Analog Input B(-)
56	VINB+	Analog Input B(+)
57	AGND	Analog Ground
58	VINA+	Analog Input A(+)
59	VINA-	Analog Input A(-)
60	AGND	Analog Ground
61	AVDD	Analog Supply Voltage
62	AVDD	Analog Supply Voltage
63	AGND	Analog Ground
64	AGND	Analog Ground

## ELECTRICAL CHARACTERISTICS TABLE (CONT'D)

### Test Conditions (Unless Otherwise Specified)

$T_A = 25^\circ\text{C}$ ,  $AV_{DD} = DV_{DD} = +3.0\text{V}$ ,  $V_{IN} = \text{GND to } +2.5\text{V}$ ,  $V_{RLF} = \text{GND}$ ,  $V_{RHF} = +2.5\text{V}$  and  $F_s = 40 \text{ MSPS}$ , 50% Duty Cycle, Differential Input Mode

Symbol	Parameter	Min.	Typ.	Max.	Unit	Conditions	
<b>DC ACCURACY</b>							
DNL	Differential Non-Linearity	-0.75	+/-0.25	.75	LSB		
INL	Integral Non-Linearity		+/-0.5		LSB		
MON	Monotonicity	No Missing Codes					Guaranteed by Test
FSE	Full Scale Error		$\pm 10$		mV	F.S. = (VRHF - VRLF)x0.97	
ZSE	Zero Scale Error		5		mV	Single Ended Mode	
<b>ANALOG INPUT</b>							
INVR	Input Voltage Range	0		VRHFx0.97	V	VRLF Grounded	
INRES	Input Resistance		20		KOhms		
INCAP	Input Capacitance		5		pF		
INBW	Input Bandwidth		400		MHz	-1dB Small Signal	
<b>REFERENCE INPUT, INTERNAL BANDGAP REFERENCE AND REFERENCE BUFFER</b>							
RLAD	Ladder Resistance	100	125	150	Ohms		
RLADTCO	Ladder Resistance Tempco		+0.8		Ohms/ $^\circ\text{C}$		
VBG	Bandgap Output Voltage Range	1.15	1.25	1.35	V		
VBGTC	Bandgap Reference Tempco		30		ppm/ $^\circ\text{C}$		
VRLF		0.0		2.0	V		
VRHF		VRLF+1.0		AVdd-0.3	V	Internal Reference Buffer	
VRHF	External Reference	VRLF+1.0		AVdd	V	External	
VRHF PSRR	Internal Reference Buffer		6		mV/V		
<b>CONVERSION AND TIMING CHARACTERISTICS (<math>C_L = 10\text{pF}</math>)</b>							
APJT	Aperture Jitter Time		12		ps	Peak-to Peak	
$t_r$	Digital Output Rise Time		3		ns		
$t_f$	Digital Output Fall Time		3		ns		
$t_{pd}$	Output Data Propagation Delay		6	14	ns	Guaranteed by Design	
$t_{den}$	Output Data Enable Delay		6	14	ns	Guaranteed by Design	
$t_{dis}$	Output Data Disable Delay		5		ns		
CLKDC	Clock Duty Cycle	40	50	60	%	Guaranteed by Design	

## ELECTRICAL CHARACTERISTICS TABLE (CONT'D)

Test Conditions (Unless Otherwise Specified)

$T_A = 25^\circ\text{C}$   $AV_{DD} = DV_{DD} = +3.0\text{V}$ ,  $V_{IN} = \text{GND to } +2.5\text{V}$ ,  $V_{RLF} = \text{GND}$ ,  $V_{RHF} = +2.5\text{V}$ , 50% Duty Cycle, Differential Input Mode

Symbol	Parameter	Min.	Typ.	Max.	Unit	Conditions
<b>DYNAMIC PERFORMANCE <math>F_s = 40\text{MHz}</math></b>						
SNR	Signal-to-Noise Ratio					Not Including Harmonics
	$f_{in} = 1.0\text{ MHz}$	57	60		dB	
	$f_{in} = 4.0\text{ MHz}$	57	60		dB	
	$f_{in} = 10.0\text{ MHz}$	56	57		dB	
SINAD	Signal-to Noise and Distortion					
	$f_{in} = 1.0\text{ MHz}$	56	58		dB	
	$f_{in} = 4.0\text{ MHz}$	56	58		dB	
	$f_{in} = 10\text{ MHz}$	56	57		dB	
<b>ENOB EFFECTIVE NUMBER OF BITS</b>						
	$f_{in} = 1.0\text{ MHz}$	9.0	9.3		Bit	
	$f_{in} = 4.0\text{ MHz}$	9.0	9.3		Bit	
	$f_{in} = 10\text{ MHz}$	9.0	9.2		Bit	
<b>SFDR SPURIOUS FREE DYNAMIC RANGE</b>						
SFDR	$f_{in} = 1.0\text{ MHz}$	70			dB	
Crosstalk	$f_{in} = 1.0\text{ MHz}$	75			dB	
IMD	$f_{in1} = 2.5\text{ MHz}$	70			dB	Intermodulation Distortion
	$f_{in2} = 3.5\text{ MHz}$					

## ELECTRICAL CHARACTERISTICS TABLE (CONT'D)

Test Conditions (Unless Otherwise Specified)

$T_A = 25^\circ\text{C}$ ,  $AV_{DD} = DV_{DD} = +3.0\text{V}$ ,  $V_{IN} = \text{GND to } +2.5\text{V}$ ,  $V_{RLF} = \text{GND}$ ,  $V_{RHF} = +2.5\text{V}$  and  $F_s = 40 \text{ MSPS}$ , 50% Duty Cycle, Differential Input Mode

Symbol	Parameter	Min.	Typ.	Max.	Unit	Conditions
<b>DIGITAL INPUTS</b>						
DVINH	Digital Input High Voltage	2.5			V	
DVINL	Digital Input Low Voltage			0.5	V	
<b>DIINH</b>	<b>Digital Input High Current (The DIFF input has an internal pull-up resistor, TRI_A, TRI_B, CLAMP and PD have internal pull-down resistors)</b>					
CKIN	Clock Input	-1.0	0.05	1.0	$\mu\text{A}$	
DIFF	Differential/Single-Ended Input	-1.0	-0.25	1.0	$\mu\text{A}$	
TRI_A/TRI_B	A/B Channel Tri-State	-125.0	-90.0	-50.0	$\mu\text{A}$	
<b>DIINL</b>	<b>Digital Input Low Current (The DIFF input has an internal pull-up resistor, TRI_A, TRI_B, CLAMP and PD have internal pull-down resistors)</b>					
CKIN	Clock Input	-5.0	0.05	5.0	nA	
DIFF	Differential/Single-Ended Input	50.0	90.0	125.0	$\mu\text{A}$	
TRI_A/TRI_B	A/B Channel Tri-State	-1.0	0.25	1.0	$\mu\text{A}$	
DINC	Digital Input capacitance		5	8	pF	
<b>DIGITAL OUTPUTS (CL = 10 pF)</b>						
DOHV	Digital Output High Voltage	DVdd -0.4V	DVdd- 0.3V		V	IOH = 1.5 mA
DOLV	Digital Output Low Voltage		0.3	0.4	V	IOL = 1.5 mA
IOZ	High-Z Leakage	-100	0.2	100	nA	



## ELECTRICAL CHARACTERISTICS TABLE (CONT'D)

### Test Conditions (Unless Otherwise Specified)

$T_A = 25^\circ\text{C}$ ,  $AV_{DD} = DV_{DD} = +3.0\text{V}$ ,  $V_{IN} = \text{GND to } +2.5\text{V}$ ,  $V_{RLF} = \text{GND}$ ,  $V_{RHF} = +2.5\text{V}$  and  $F_s = 40 \text{ MSPS}$ , 50% Duty Cycle, Differential Input Mode

Symbol	Parameter	Min.	Typ.	Max.	Unit	Conditions
<b>POWER SUPPLIES</b>						
$AV_{DD}$	Analog Power Supply Voltage	2.7	3.0	3.3	V	
$DV_{DD}$	Digital Power Supply Range		$AV_{DD}$		V	$DV_{DD} = AV_{DD}$
<b><math>F_s = 40 \text{ MHz}</math>, <math>AV_{DD} = DV_{DD} = 2.7\text{V}</math>, <math>CL = 10\text{pF}</math>, <math>F_{in} = 10\text{MHz}</math> (Includes <math>I_{ref}</math> Current)</b>						
AIDD	Analog Supply Current		55		mA	
DIDD	Digital Supply Current		13		mA	
DOIDD	Output Driver Current		6		mA	
PDISS	Power Dissipation		225		mW	
<b><math>F_s = 40 \text{ MHz}</math>, <math>AV_{DD} = DV_{DD} = 3.0\text{V}</math>, <math>CL = 10\text{pF}</math>, <math>F_{in} = 10\text{MHz}</math> (Includes <math>I_{ref}</math> Current)</b>						
AIDD	Analog Supply Current		37		mA	
DIDD	Digital Supply Current		15		mA	
DOIDD	Output Driver Current		15		mA	
PDISS	Power Dissipation		200		mW	
<b>POWER DOWN CURRENT</b>						
IPD	Power Down Current		100		$\mu\text{A}$	

## ABSOLUTE MAXIMUM RATINGS ( $T_A = +25^\circ\text{C}$ unless otherwise noted)<sup>1, 2, 3</sup>

$V_{DD}$ to GND. . . . .	+7.0V	Lead Temperature (Soldering 10 seconds). . . . .	300°C
$V_{RT}$ & $V_{RB}$ . . . . .	$V_{DD} +0.5$ to GND -0.5V	Maximum Junction Temperature . . . . .	150°C
$V_{IN}$ . . . . .	$V_{DD} +0.5$ to GND -0.5V	Package Power Dissipation Ratings ( $T_A = +70^\circ\text{C}$ )	
All Inputs. . . . .	$V_{DD} +0.5$ to GND -0.5V	SSOP. . . . .	$\theta_{JA} = 89.4^\circ\text{C/W}$
All Outputs. . . . .	$V_{DD} +0.5$ to GND -0.5V	ESD . . . . .	2000V min
Storage Temperature. . . . .	-65°C to 150°C		

### Notes:

- <sup>1</sup> Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation at or above this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.
- <sup>2</sup> Any input pin which can see a value outside the absolute maximum ratings should be protected by Schottky diode clamps (HP5082-2835) from input pin to the supplies. All inputs have protection diodes which will protect the device from short transients outside the supplies of less than 100mA for less than 100ms.
- <sup>3</sup>  $V_{DD}$  refers to  $AV_{DD}$  and  $DV_{DD}$ . GND refers to AGND and DGND

**Figure 1 - SINAD vs.  $F_{in}$  and  $V_{dd}$  @  
 $F_c = 40.0\text{MHz}$ , DIFFERENTIAL INPUT MODE**

**Figure 2 - FFT Spectrum @  $F_{clock} = 40.0\text{MHz}$ ,  
 $F_{in} = 4.0\text{MHz}$ , DIFFERENTIAL INPUT MODE**

**Figure 3 - FFT Spectrum @  $F_{clock} = 40.0\text{MHz}$ ,  
 $F_{in} = 10.0\text{MHz}$ , DIFFERENTIAL INPUT MODE**

**Figure 4 - SINAD vs.  $F_{in}$  and  $V_{dd}$  @  
 $F_c = 40.0\text{MHz}$ , SINGLE-ENDED INPUT MODE**

**Figure 5 - FFT Spectrum @Fclock = 40.0MHz,  
Fin = 4.0MHz, Single-ended INPUT MODE**

**Figure 6 - FFT Spectrum @Fclock = 40.0MHz, Fin  
= 10.0MHz, Single-ended INPUT MODE**

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